

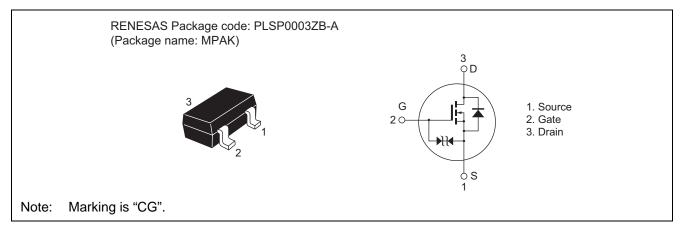
RQK0603CGDQA

Silicon N Channel MOS FET Power Switching R07DS0307EJ0500 (Previous: REJ03G1277-0400) Rev.5.00 Mar 28, 2011

Features

- Low on-resistance
- $R_{DS(on)} = 212 \text{ m}\Omega \text{ typ } (V_{GS} = 10 \text{ V}, I_D = 1 \text{ A})$
- Low drive current
- High speed switching
- 4.5 V gate drive

Outline



Absolute Maximum Ratings

			$(Ta = 25^{\circ}C)$
ltem	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	60	V
Gate to source voltage	V _{GSS}	±20	V
Drain current	ID	2	А
Drain peak current	I _{D(Pulse)} Note1	5	А
Body - drain diode reverse drain current	I _{DR}	2	А
Channel dissipation	Pch ^{Note2}	0.8	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. When using the glass epoxy board (FR-4: 40 \times 40 \times 1 mm)



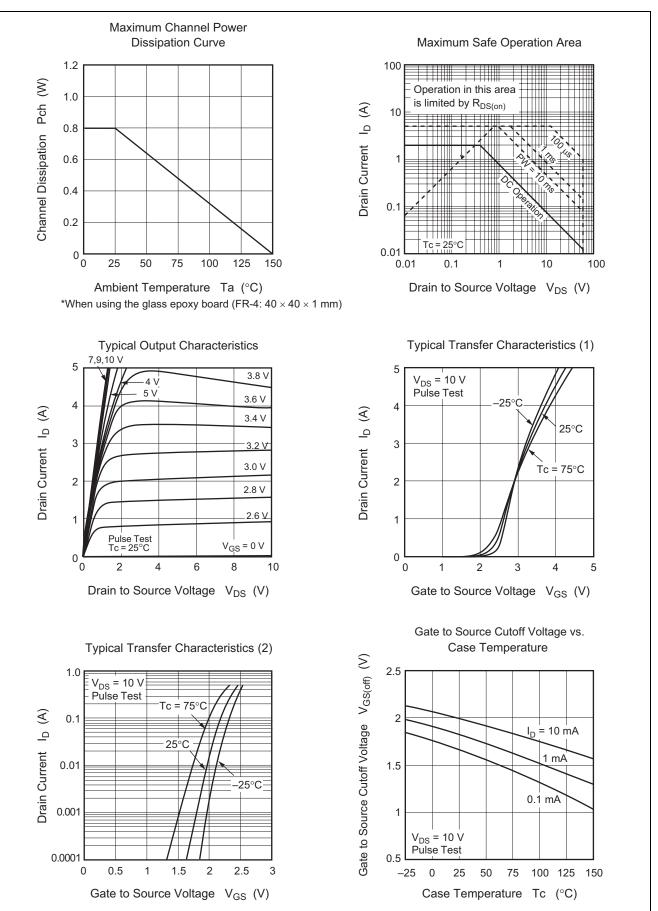
Electrical Characteristics

						$(Ta = 25^{\circ}C)$	
Item	Symbol	Min	Тур	Max	Unit	Test conditions	
Drain to source breakdown voltage	V _{(BR)DSS}	60	_		V	$I_D = 10 \text{ mA}, V_{GS} = 0$	
Gate to source breakdown voltage	V _{(BR)GSS}	±20	_		V	$I_G = \pm 100 \ \mu A, \ V_{DS} = 0$	
Gate to source leak current	I _{GSS}	_	—	±10	μΑ	$V_{GS}=\ \pm 16\ V,\ V_{DS}=0$	
Drain to source leak current	I _{DSS}	_	—	1	μΑ	$V_{DS} = 60 V, V_{GS} = 0$	
Gate to source cutoff voltage	V _{GS(off)}	1.0	—	2.0	V	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$	
Drain to source on state resistance	R _{DS(on)}	_	212	265	mΩ	$I_D = 1 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note3}}$	
	R _{DS(on)}	_	248	348	mΩ	$I_D = 1 \text{ A}, V_{GS} = 4.5 \text{ V}^{Note3}$	
Forward transfer admittance	y _{fs}	1.6	2.7	_	S	$I_D = 1 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note3}}$	
Input capacitance	Ciss	_	130	_	pF	$V_{DS} = 10 V, V_{GS} = 0,$	
Output capacitance	Coss	_	24	_	pF	f = 1 MHz	
Reverse transfer capacitance	Crss		9		pF		
Turn - on delay time	t _{d(on)}	_	7.3	_	ns	$I_D = 0.75 \text{ A}, V_{GS} = 10 \text{ V},$	
Rise time	tr	_	35	_	ns	$R_L = 13 \Omega$, $Rg = 4.7 \Omega$	
Turn - off delay time	t _{d(off)}	_	44	_	ns		
Fall time	t _f	_	6.5	_	ns		
Total gate charge	Qg	_	2.8	_	nC	$V_{DD} = 10 \text{ V}, \text{ V}_{GS} = 10 \text{ V},$	
Gate to source charge	Qgs	_	0.4	_	nC	$I_D = 2 A$	
Gate to drain charge	Qgd	_	0.4	_	nC		
Body - drain diode forward voltage	V _{DF}		0.9	—	V	$I_F = 1.5 \text{ A}, V_{GS} = 0^{Note3}$	

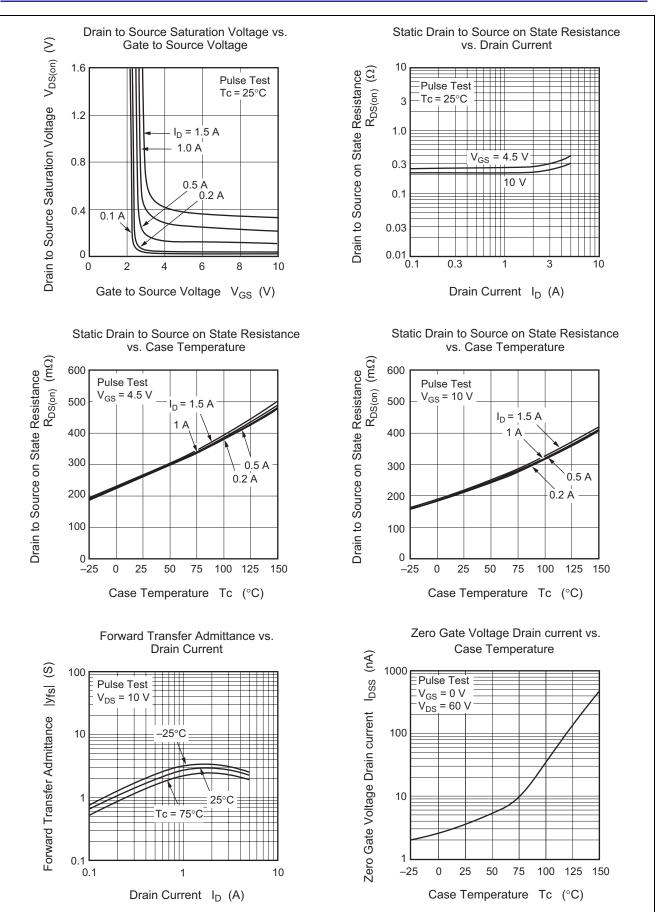
Notes: 3. Pulse test



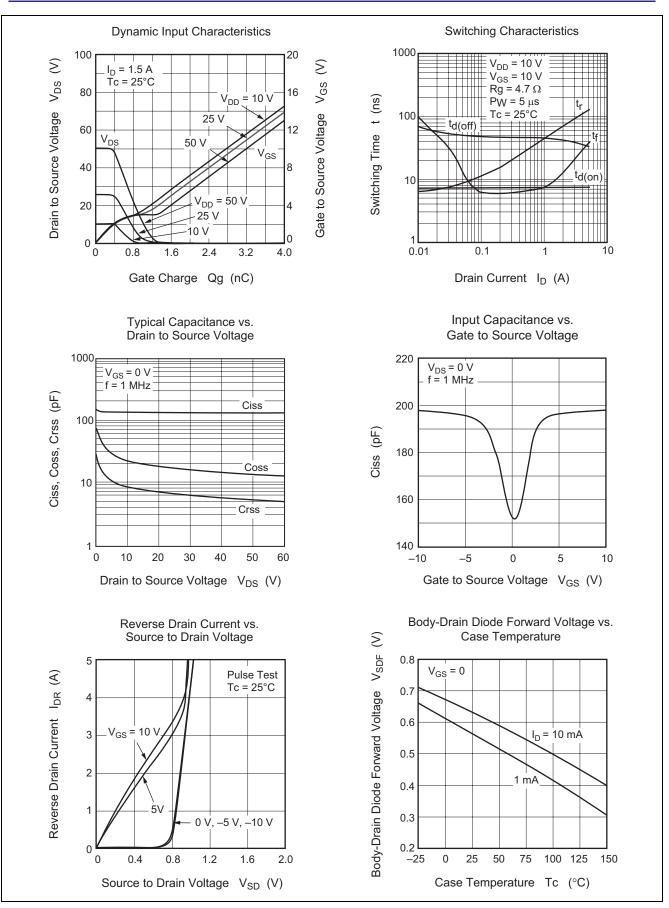
Main Characteristics



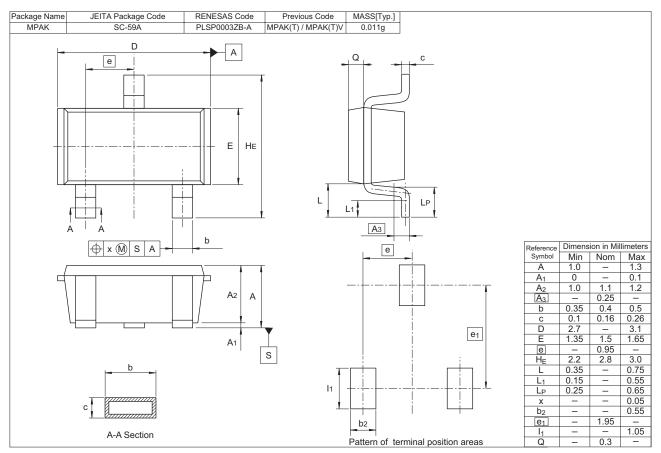








Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RQK0603CGDQATL-H	3000 pcs.	φ178 mm reel, 8 mm Emboss taping



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